
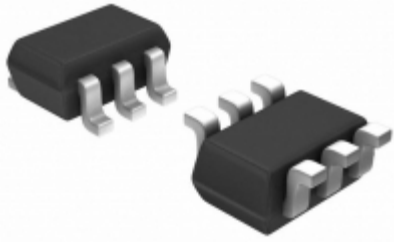
	<h2>SI1428EDH-T1-GE3</h2>
	<p>Hersteller-Teilenummer: SI1428EDH-T1-GE3</p> <p>Hersteller / Marke: Electro-Films (EFI) / Vishay</p> <p>Teil der Beschreibung: MOSFET N-CHANNEL 30V 4A SC70-6</p> <p>Datenblätter:  SI1428EDH-T1-GE3.pdf</p> <p>RoHs Status:</p> <p>Lagerzustand: New original, 15396 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SI1428EDH-T1-GE3
Hersteller	Electro-Films (EFI) / Vishay
Beschreibung	MOSFET N-CHANNEL 30V 4A SC70-6
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	15396 pcs Stock
detaillierte Beschreibung	N-Channel 30V 4A (Tc) 2.8W (Tc) Surface Mount SC-
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	6-TSSOP, SC-88, SOT-363
Supplier Device-Gehäuse	SC-70-6
Verlustleistung (max)	2.8W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	30V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	4A (Tc)
Rds On (Max) @ Id, Vgs	45 mOhm @ 3.7A, 10V
VGS (th) (Max) @ Id	1.3V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	13.5nC @ 10V
Antriebsspannung (Max Rds On, Min Rds On)	2.5V, 10V
Vgs (Max)	±12V
Verpackung	Tape & Reel (TR)



























SI1428EDH-T1-GE3 ist neu im Original, Suche SI1428EDH-T1-GE3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI1428EDH-T1-GE3 Electro-Films (EFI) / Vishay mit Garantie und Vertrauen. Anfrage SI1428EDH-T1-GE3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SI1431DH-T1-GE3 Vishay / Siliconix MOSFET P-CH 30V 1.7A SOT363</p>	 <p>SI1427EDH-T1-GE3 Vishay / Siliconix MOSFET P-CH 20V 2A SOT-363</p>	 <p>SI1428EDH-T1-GE3 VISHAY VISHAY SC70-6</p>	 <p>SI1426DH-T1-GE3 Vishay / Siliconix MOSFET N-CH 30V 2.8A SC-70-6</p>
 <p>SI1426DH-T1-E3 Vishay / Siliconix MOSFET N-CH 30V 2.8A SC70-6</p>	 <p>SI1426DH-T1-GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 30V 2.8A SC-70-6</p>	 <p>SI1431DH-T1-E3 Vishay / Siliconix MOSFET P-CH 30V 1.7A SOT363</p>	 <p>SI1431DH-T1-E3 Electro-Films (EFI) / Vishay MOSFET P-CH 30V 1.7A SOT363</p>

heiße Teile

Mehr

 SI1413EDH-T1-E3	 SI1413EDH-T1-E3	 SI1413EDH-T1-GE3	 SI1413EDH-T1-GE3	 SI1414DH-T1-GE3
 SI1414DH-T1-GE3	 SI1416EDH-T1-GE3	 SI1416EDH-T1-GE3	 SI1417DH-T1-E3	 SI1417DH-T1-GE3
 SI1417EDH-T1	 SI1417EDH-T1-E3	 SI1417EDH-T1-E3	 SI1417EDH-T1-GE3	 SI1417EDH-T1-GE3
 SI1422DH-T1-GE3	 SI1422DH-T1-GE3	 SI1424EDH-T1-GE3	 SI1424EDH-T1-GE3	 SI1426DH-T1-E3
 SI1426DH-T1-E3	 SI1426DH-T1-GE3	 SI1426DH-T1-GE3	 SI1427EDH-T1-GE3	 SI1427EDH-T1-GE3
 SI1428EDH-T1-GE3	 SI1433DH-T1	 SI1433DH-T1-E3	 SI1433DH-T1-E3	 SI1433DH-T1-GE3
 SI1433DH-T1-GE3	 SI1441EDH-T1-GE3	 SI1441EDH-T1-GE3	 SI1442DH-T1-GE3	 SI1442DH-T1-GE3
 SI1443EDH-T1-GE3	 SI1443EDH-T1-GE3	 SI1467DH-T1-GE3	 SI1467DH-T1-GE3	 SI1469DH-T1-GE3
 SI1469DH-T1-GE3	 SI1470DH-M6TR	 SI1470DH-T1-GE3	 SI1470DH-T1-GE3	 SI1471DH-T1
 SI1471DH-T1-E3	 SI1471DH-T1-E3	 SI1471DH-T1-GE3	 SI1471DH-T1-GE3	 SI1472DH-T1-E3

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